





LMT86 SNIS169F - MARCH 2013 - REVISED MAY 2024

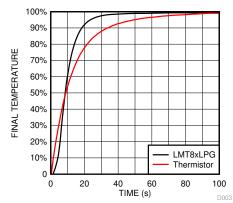
# LMT86 2.2V, SC70/TO-92/TO-92S, **Analog Temperature Sensor**

#### 1 Features

- LMT86LPG (TO-92S package) has a Fast Thermal Time Constant, 10s Typical (1.2m/s Airflow)
- Very accurate: ±0.4°C typical
- Low 2.2V operation
- Average sensor gain of -10.9mV/°C
- Low 5.4µA quiescent current
- Wide temperature range: -50°C to 150°C
- Output is short-circuit protected
- Push-pull output with ±50µA drive capability
- Footprint compatible with the industry-standard LM20/19 and LM35 temperature sensors
- Cost-effective alternative to thermistors

# 2 Applications

- Infotainment and cluster
- Powertrain systems
- Smoke and heat detectors
- **Drones**
- **Appliances**



\* Fast thermal response NTC

**Thermal Time Constant** 

# 3 Description

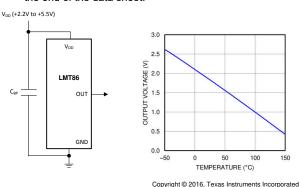
The LMT86 are precision CMOS temperature sensors with ±0.4°C typical accuracy (±2.7°C maximum) and a linear analog output voltage that is inversely proportional to temperature. The 2.2V supply voltage operation, 5.4µA quiescent current, and 0.7ms poweron time enable effective power-cycling architectures to minimize power consumption for battery-powered applications such as drones and sensor nodes. The LMT86LPG through-hole TO-92S package fast thermal time constant supports off-board timetemperature sensitive applications such as smoke and heat detectors. The accuracy over the wide operating range and other features make the LMT86 an excellent alternative to thermistors.

For devices with different average sensor gains and comparable accuracy, refer to Comparable Alternative Devices for alternative devices in the LMT8x family.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
LMT86	SOT (5)	2.00mm × 1.25mm		
LIVITOO	TO-92 (3)	4.30mm × 3.50mm		

For all available packages, see the orderable addendum at the end of the data sheet.



**Output Voltage vs Temperature** 



# **Table of Contents**

1 Features1	7.4 Device Functional Modes10
2 Applications1	8 Application and Implementation12
3 Description	8.1 Application Information12
4 Device Comparison2	8.2 Typical Applications12
5 Pin Configuration and Functions3	9 Power Supply Recommendations13
6 Specifications4	10 Layout14
6.1 Absolute Maximum Ratings4	10.1 Layout Guidelines14
6.2 ESD Ratings4	10.2 Layout Example14
6.3 Recommended Operating Conditions4	11 Device and Documentation Support15
6.4 Thermal Information4	11.1 Receiving Notification of Documentation Updates 15
6.5 Accuracy Characteristics5	11.2 Support Resources15
6.6 Electrical Characteristics5	11.3 Trademarks15
6.7 Typical Characteristics6	11.4 Electrostatic Discharge Caution15
7 Detailed Description8	11.5 Glossary15
7.1 Overview8	12 Revision History15
7.2 Functional Block Diagram8	13 Mechanical, Packaging, and Orderable
7.3 Feature Description8	Information16

# **4 Device Comparison**

Table 4-1. Available Device Packages

ORDER NUMBER <sup>(1)</sup>	PACKAGE	PIN	BODY SIZE (NOM)	MOUNTING TYPE
LMT86DCK	SOT (AKA <sup>(2)</sup> : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount
LMT86LP	TO-92 (AKA <sup>(2)</sup> : LP)	3	4.30 mm × 3.50 mm	Through-hole; straight leads
LMT86LPG	TO-92S (AKA <sup>(2)</sup> : LPG)	3	4.00 mm × 3.15 mm	Through-hole; straight leads
LMT86LPM	TO-92 (AKA <sup>(2)</sup> : LPM)	3	4.30 mm × 3.50 mm	Through-hole; formed leads
LMT86DCK-Q1	SOT (AKA <sup>(2)</sup> : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount

- (1) For all available packages and complete order numbers, see the Package Option addendum at the end of the data sheet.
- (2) AKA = Also Known As

**Table 4-2. Comparable Alternative Devices** 

DEVICE NAME	AVERAGE OUTPUT SENSOR GAIN	POWER SUPPLY RANGE
LMT84	−5.5 mV/°C	1.5 V to 5.5 V
LMT85	−8.2 mV/°C	1.8 V to 5.5 V
LMT86	−10.9 mV/°C	2.2 V to 5.5 V
LMT87	−13.6 mV/°C	2.7 V to 5.5 V

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Product Folder Links: LMT86



# **5 Pin Configuration and Functions**

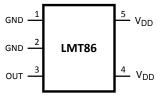


Figure 5-1. 5-Pin SOT (SC70) DCK Package (TOP VIEW)

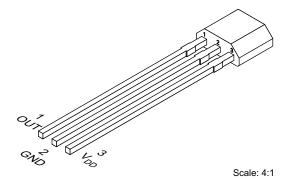


Figure 5-2. LPG Package 3-Pin TO-92S (Top View)

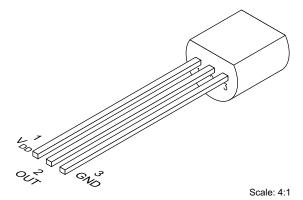
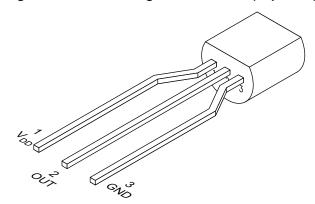


Figure 5-3. LP Package 3-Pin TO-92 (Top View)



Scale: 4:1

Figure 5-4. LPM Package 3-Pin TO-92 (Top View)

Table 5-1. Pin Functions

	Table 5-1.1 III Full Culous										
	P	IN		TYPE	DESCRIPTION						
NAME			ITPE	EQUIVALENT CIRCUIT	FUNCTION						
GND	1, 2 <sup>(1)</sup>	3	2	Ground	N/A	Power Supply Ground					
OUT	3	2	1	Analog Output	V <sub>DD</sub> GND	Outputs a voltage that is inversely proportional to temperature					
$V_{DD}$	4, 5	1	3	Power	N/A	Positive Supply Voltage					

(1) Direct connection to the back side of the die



# **6 Specifications**

# **6.1 Absolute Maximum Ratings**

#### See (1) (2)

	MIN	MAX	UNIT
Supply voltage	-0.3	6	V
Voltage at output pin	-0.3	(V <sub>DD</sub> + 0.5)	V
Output current	-7	7	mA
Input current at any pin (3)	<b>–</b> 5	5	mA
Maximum junction temperature (T <sub>JMAX</sub> )		150	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
- (2) Soldering process must comply with TI's Reflow Temperature Profile specifications. Refer to www.ti.com/packaging. Reflow temperature profiles are different for lead-free and non-lead-free packages.
- (3) When the input voltage (V<sub>I</sub>) at any pin exceeds power supplies (V<sub>I</sub> < GND or V<sub>I</sub> > V), the current at that pin should be limited to 5 mA.

## 6.2 ESD Ratings

			VALUE	UNIT					
LMT86LP in TO-92 package									
V =	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup> (2)		V						
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(3)</sup>	±1000	<b>v</b>					
LMT86D0	LMT86DCK in SC70 package								
V	Electrostatic discharge	Human-body model (HBM), per JESD22-A114 <sup>(2)</sup>	±2500	V					
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(3)</sup>	±1000	V					

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) The human body model is a 100-pF capacitor discharged through a 1.5-k $\Omega$  resistor into each pin.
- (3) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### **6.3 Recommended Operating Conditions**

	MIN	MAX	UNIT
Specified temperature	$T_{MIN} \le T_A \le T_{MAX}$		°C
Specified temperature	-50 ≤ T <sub>A</sub> ≤ 150		°C
Supply voltage (V <sub>DD</sub> )	2.2	5.5	V

### **6.4 Thermal Information**

		LMT86	LMT86LP	LMT86LPG	
	THERMAL METRIC <sup>(1)</sup> (2)	DCK (SOT/SC70)	LP/LPM (TO-92)	LPG (TO-92S)	UNIT
		5 PINS	3 PINS	3 PINS	
R <sub>0JA</sub>	Junction-to-ambient thermal resistance (3) (4)	275	167	130.4	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	84	90	64.2	°C/W
R <sub>0JB</sub>	Junction-to-board thermal resistance	56	146	106.2	°C/W
ΨЈТ	Junction-to-top characterization parameter	1.2	35	14.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	55	146	106.2	°C/W

- (1) For information on self-heating and thermal response time, see section Mounting and Thermal Conductivity.
- (2) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report.
- The junction to ambient thermal resistance (R<sub>0JA</sub>) under natural convection is obtained in a simulation on a JEDEC-standard, High-K board as specified in JESD51-7, in an environment described in JESD51-2. Exposed pad packages assume that thermal vias are included in the PCB, per JESD 51-5.
- (4) Changes in output due to self-heating can be computed by multiplying the internal dissipation by the thermal resistance.

Product Folder Links: LMT86

## 6.5 Accuracy Characteristics

These limits do not include DC load regulation. These stated accuracy limits are with reference to the values in Table 7-1.

PARAMETER	CONDITIONS	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
	40°C to 150°C; V <sub>DD</sub> = 2.2 V to 5.5 V	-2.7	±0.4	2.7	°C
	0°C to 40°C; V <sub>DD</sub> = 2.4 V to 5.5 V	-2.7	±0.7	2.7	°C
Temperature accuracy <sup>(3)</sup>	0°C to 70°C; V <sub>DD</sub> = 3.0 V to 5.5 V		±0.3		°C
	–50°C to 0°C; V <sub>DD</sub> = 3.0 V to 5.5 V	-2.7	±0.7	2.7	°C
	-50°C to 0°C; V <sub>DD</sub> = 3.6 V to 5.5 V		±0.25		°C

- (1) Limits are specified to TI's AOQL (Average Outgoing Quality Level).
- (2) Typicals are at  $T_J = T_A = 25^{\circ}$ C and represent most likely parametric norm.
- (3) Accuracy is defined as the error between the measured and reference output voltages, tabulated in the Transfer Table at the specified conditions of supply gain setting, voltage, and temperature (expressed in °C). Accuracy limits include line regulation within the specified conditions. Accuracy limits do not include load regulation; they assume no dc load.

### 6.6 Electrical Characteristics

Unless otherwise noted, these specifications apply for  $+V_{DD}$  = 2.2 V to 5.5 V. MIN and MAX limits apply for  $T_A$  =  $T_J$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted; typical values apply for  $T_A$  =  $T_J$  = 25°C.

	PARAMETER	TEST CONDITIONS	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
	Average sensor gain (output transfer function slope)	-30°C and 90°C used to calculate average sensor gain		-10.9		mV/°C
Load regulation (3)		Source $\leq$ 50 $\mu$ A, $(V_{DD} - V_{OUT}) \geq$ 200 mV	-1	-0.22		mV
		Sink ≤ 50 μA, V <sub>OUT</sub> ≥ 200 mV		0.26	1	mV
	Line regulation <sup>(4)</sup>			200		μV/V
	Cupply ourrant	$T_A = 30^{\circ}C \text{ to } 150^{\circ}C, (V_{DD} - V_{OUT}) \ge 100 \text{ mV}$		5.4	8.1	μΑ
IS	Supply current	$T_A = -50^{\circ}C \text{ to } 150^{\circ}C, (V_{DD} - V_{OUT}) \ge 100 \text{ mV}$		5.4	9	μΑ
CL	Output load capacitance			1100		pF
	Power-on time <sup>(5)</sup>	C <sub>L</sub> = 0 pF to 1100 pF		0.7	1.9	ms
	Output drive	$T_A = T_J = 25$ °C	-50		50	μΑ

- (1) Limits are specific to TI's AOQL (Average Outgoing Quality Level).
- (2) Typicals are at  $T_J = T_A = 25^{\circ}$ C and represent most likely parametric norm.
- (3) Source currents are flowing out of the LMT86. Sink currents are flowing into the LMT86.
- (4) Line regulation (DC) is calculated by subtracting the output voltage at the highest supply voltage from the output voltage at the lowest supply voltage. The typical DC line regulation specification does not include the output voltage shift discussed in Output Voltage Shift.
- (5) Specified by design and characterization.



# **6.7 Typical Characteristics**

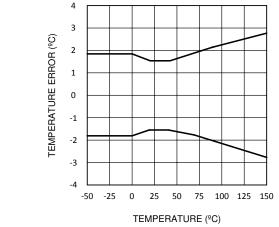


Figure 6-1. Temperature Error vs Temperature

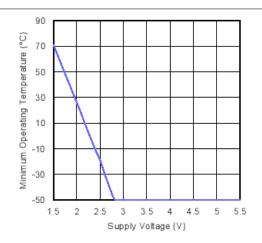


Figure 6-2. Minimum Operating Temperature vs Supply Voltage

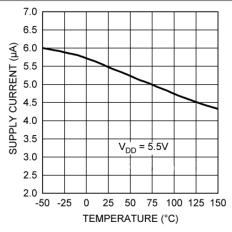


Figure 6-3. Supply Current vs Temperature

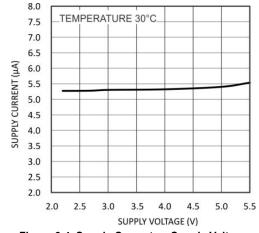
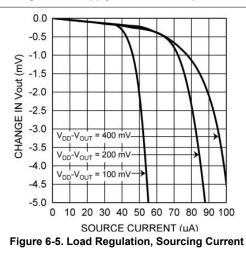


Figure 6-4. Supply Current vs Supply Voltage



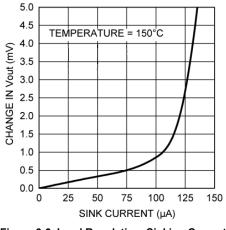


Figure 6-6. Load Regulation, Sinking Current



# **6.7 Typical Characteristics (continued)**

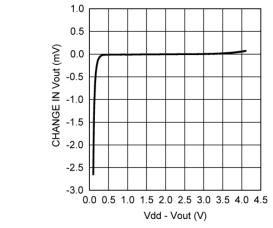


Figure 6-7. Change in V<sub>OUT</sub> vs Overhead Voltage

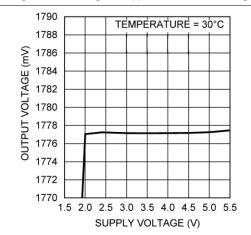


Figure 6-9. Output Voltage vs Supply Voltage

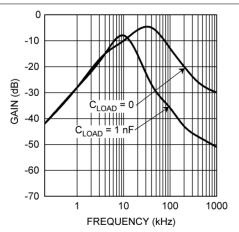


Figure 6-8. Supply-Noise Gain vs Frequency

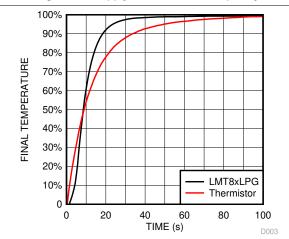


Figure 6-10. LMT86LPG Thermal Response vs Common Leaded Thermistor With 1.2-m/s Airflow



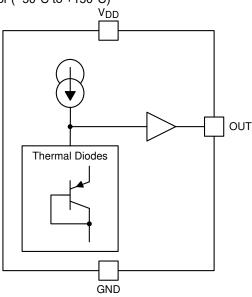
# 7 Detailed Description

#### 7.1 Overview

The LMT86 is an analog output temperature sensor. The temperature-sensing element is comprised of a simple base emitter junction that is forward biased by a current source. The temperature-sensing element is then buffered by an amplifier and provided to the OUT pin. The amplifier has a simple push-pull output stage thus providing a low impedance output source.

### 7.2 Functional Block Diagram

Full-Range Celsius Temperature Sensor (-50°C to +150°C)



# 7.3 Feature Description

#### 7.3.1 LMT86 Transfer Function

Table 7-1 shows the output voltage of the LMT86 across the complete operating temperature range. This table is the reference from which the LMT86 accuracy specifications (listed in the Accuracy Characteristics table) are determined. This table can be used, for example, in a host processor look-up table. A file containing this data is available for download at LMT86 product folder under Tools and Software Models.

TEMP (°C) TEMP (°C) TEMP TEMP V<sub>OUT</sub> (mV) TEMP V<sub>OUT</sub> (mV) V<sub>OUT</sub> (mV) V<sub>OUT</sub> (mV) V<sub>OUT</sub> (mV) (°C) (°C) (°C) -10 -9 -49 -48 -8 -47 -7 -46 -6 -45 -5 -44 -4 -3 -43 -2 -41 -1 -40 -39 -38 -37 -36 

Table 7-1. LMT86 Transfer Table

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-35

-34

420

Table 7-1. LMT86 Transfer Table (continued)

Table 7-1. LMT86 Transfer Table (continued)												
TEMP (°C)	V <sub>OUT</sub> (mV)	TEMP (°C)	V <sub>OUT</sub> (mV)		TEMP (°C)	V <sub>OUT</sub> (mV)		TEMP (°C)	V <sub>OUT</sub> (mV)		TEMP (°C)	V <sub>OUT</sub> (mV)
-33	2449	7	2025		47	1591		87	1144		127	688
-32	2439	8	2014		48	1580		88	1133		128	676
-31	2429	9	2004		49	1569		89	1122		129	665
-30	2418	10	1993		50	1558		90	1110		130	653
-29	2408	11	1982		51	1547		91	1099		131	642
-28	2397	12	1971		52	1536		92	1088		132	630
-27	2387	13	1961		53	1525		93	1076		133	618
-26	2376	14	1950		54	1514		94	1065		134	607
-25	2366	15	1939		55	1503		95	1054		135	595
-24	2355	16	1928		56	1492		96	1042		136	584
-23	2345	17	1918		57	1481		97	1031		137	572
-22	2334	18	1907		58	1470		98	1020		138	560
-21	2324	19	1896		59	1459		99	1008		139	549
-20	2313	20	1885		60	1448		100	997		140	537
-19	2302	21	1874		61	1436		101	986		141	525
-18	2292	22	1864		62	1425		102	974		142	514
-17	2281	23	1853		63	1414		103	963		143	502
-16	2271	24	1842		64	1403		104	951		144	490
-15	2260	25	1831		65	1391		105	940		145	479
-14	2250	26	1820		66	1380		106	929		146	467
-13	2239	27	1810		67	1369		107	917		147	455
-12	2228	28	1799		68	1358		108	906		148	443
-11	2218	29	1788		69	1346		109	895		149	432
				$\overline{}$	+	+	+	<del></del>	+	-		+

Although the LMT86 is very linear, its response does have a slight umbrella parabolic shape. This shape is very accurately reflected in Table 7-1. The Transfer Table can be calculated by using the parabolic equation (Equation 1).

$$V_{TEMP}(mV) = 1777.3mV - \left[10.888 \frac{mV}{^{\circ}C} (T - 30^{\circ}C)\right] - \left[0.00347 \frac{mV}{^{\circ}C^{2}} (T - 30^{\circ}C)^{2}\right]$$
(1)

The parabolic equation is an approximation of the transfer table and the accuracy of the equation degrades slightly at the temperature range extremes. Equation 1 can be solved for T resulting in:

$$T = \frac{10.888 - \sqrt{(-10.888)^2 + 4 \times 0.00347 \times (1777.3 - V_{TEMP} (mV))}}{2 \times (-0.00347)} + 30$$
 (2)

For an even less accurate linear approximation, a line can easily be calculated over the desired temperature range from the table using the two-point equation (Equation 3):

$$V - V_1 = \left(\frac{V_2 - V_1}{T_2 - T_1}\right) \times (T - T_1)$$
(3)

#### where

- V is in mV,
- T is in °C,
- T<sub>1</sub> and V<sub>1</sub> are the coordinates of the lowest temperature,
- and T<sub>2</sub> and V<sub>2</sub> are the coordinates of the highest temperature.

For example, if the user wanted to resolve this equation, over a temperature range of 20°C to 50°C, they would proceed as follows:



$$V - 1885 \text{ mV} = \left(\frac{1558 \text{ mV} - 1885 \text{ mV}}{50^{\circ}\text{C} - 20^{\circ}\text{C}}\right) \times (\text{T} - 20^{\circ}\text{C})$$
(4)

$$V - 1885 \text{ mV} = (-10.9 \text{ mV} / {}^{\circ}\text{C}) \times (\text{T} - 20 {}^{\circ}\text{C})$$
 (5)

$$V = (-10.9 \text{ mV} / {}^{\circ}\text{C}) \times \text{T} + 2103 \text{ mV}$$
 (6)

Using this method of linear approximation, the transfer function can be approximated for one or more temperature ranges of interest.

### 7.4 Device Functional Modes

### 7.4.1 Mounting and Thermal Conductivity

The LMT86 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface.

To ensure good thermal conductivity, the backside of the LMT86 die is directly attached to the GND pin. The temperatures of the lands and traces to the other leads of the LMT86 will also affect the temperature reading.

Alternatively, the LMT86 can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the LMT86 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. If moisture creates a short circuit from the output to ground or  $V_{DD}$ , the output from the LMT86 will not be correct. Printed-circuit coatings are often used to ensure that moisture cannot corrode the leads or circuit traces.

The thermal resistance junction to ambient ( $R_{\theta JA}$  or  $\theta_{JA}$ ) is the parameter used to calculate the rise of a device junction temperature due to its power dissipation. Use Equation 7 to calculate the rise in the LMT86 die temperature:

$$T_{J} = T_{A} + \theta_{JA} \left[ (V_{DD}I_{S}) + (V_{DD} - V_{O}) I_{L} \right]$$
(7)

#### where

- T<sub>A</sub> is the ambient temperature,
- I<sub>S</sub> is the supply current,
- · ILis the load current on the output,
- and  $V_O$  is the output voltage.

For example, in an application where  $T_A$  = 30°C,  $V_{DD}$  = 5 V,  $I_S$  = 5.4  $\mu A$ ,  $V_O$  = 1777 mV junction temp 30.014°C self-heating error of 0.014°C. Because the junction temperature of the LMT86 is the actual temperature being measured, take care to minimize the load current that the LMT86 is required to drive. The *Thermal Information* <sup>1</sup> table shows the thermal resistance of the LMT86.

#### 7.4.2 Output Noise Considerations

A push-pull output gives the LMT86 the ability to sink and source significant current. This is beneficial when, for example, driving dynamic loads like an input stage on an analog-to-digital converter (ADC). In these applications the source current is required to quickly charge the input capacitor of the ADC. The LMT86 is ideal for this and other applications which require strong source or sink current.

The LMT86 supply-noise gain (the ratio of the AC signal on V<sub>OUT</sub> to the AC signal on V<sub>DD</sub>) was measured during bench tests. Figure 6-8 shows the typical attenuation found in the Typical Characteristics section. A load capacitor on the output can help to filter noise.

For operation in very noisy environments, some bypass capacitance should be present on the supply within approximately 5 centimeters of the LMT86.

For information on self-heating and thermal response time, see section Mounting and Thermal Conductivity.



#### 7.4.3 Capacitive Loads

The LMT86 handles capacitive loading well. In an extremely noisy environment, or when driving a switched sampling input on an ADC, it may be necessary to add some filtering to minimize noise coupling. Without any precautions, Figure 7-1 shows how the LMT86 can drive a capacitive load less than or equal to 1100 pF. For capacitive loads greater than 1100 pF, Figure 7-2 shows how a series resistor may be required on the output.

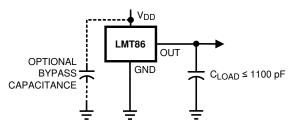


Figure 7-1. LMT86 No Decoupling Required for Capacitive Loads Less Than 1100 pF

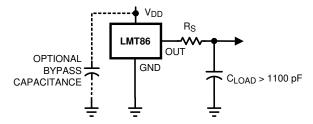


Figure 7-2. LMT86 With Series Resistor for Capacitive Loading Greater Than 1100 pF

C <sub>LOAD</sub>	MINIMUM R <sub>S</sub>
1.1 nF to 99 nF	3 kΩ
100 nF to 999 nF	1.5 kΩ
1 μF	800 Ω

Table 7-2. Recommended Series Resistor Values

### 7.4.4 Output Voltage Shift

The LMT86 device is very linear over temperature and supply voltage range. Due to the intrinsic behavior of an NMOS/PMOS rail-to-rail buffer, a slight shift in the output can occur when the supply voltage is ramped over the operating range of the device. The location of the shift is determined by the relative levels of  $V_{DD}$  and  $V_{OUT}$ . The shift typically occurs when  $V_{DD} - V_{OUT} = 1 \text{ V}$ .

This slight shift (a few millivolts) takes place over a wide change (approximately 200 mV) in  $V_{DD}$  or  $V_{OUT}$ . Because the shift takes place over a wide temperature change of 5°C to 20°C,  $V_{OUT}$  is always monotonic. The accuracy specifications in the *Accuracy Characteristics* table already include this possible shift.

# 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

# 8.1 Application Information

The LMT86 features make it suitable for many general temperature-sensing applications. It can operate down to 2.2-V supply with 5.4-µA power consumption, making it ideal for battery-powered devices. Package options like the through-hole TO-92 package allow the LMT86 to be mounted onboard, off-board, to a heat sink, or on multiple unique locations in the same application.

# 8.2 Typical Applications

#### 8.2.1 Connection to an ADC

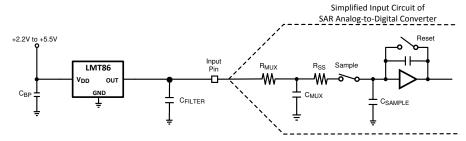


Figure 8-1. Suggested Connection to a Sampling Analog-to-Digital Converter Input Stage

#### 8.2.1.1 Design Requirements

Most CMOS ADCs found in microcontrollers and ASICs have a sampled data comparator input structure. When the ADC charges the sampling cap, it requires instantaneous charge from the output of the analog source such as the LMT86 temperature sensor and many op amps. This requirement is easily accommodated by the addition of a capacitor, C<sub>FILTER</sub>.

#### 8.2.1.2 Detailed Design Procedure

The size of  $C_{FILTER}$  depends on the size of the sampling capacitor and the sampling frequency. Because not all ADCs have identical input stages, the charge requirements will vary. This general ADC application is shown as an example only.

#### 8.2.1.3 Application Curve

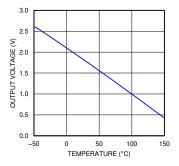


Figure 8-2. Analog Output Transfer Function

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### 8.2.2 Conserving Power Dissipation With Shutdown

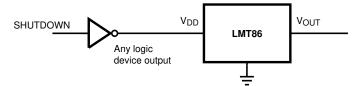


Figure 8-3. Conserving Power Dissipation With Shutdown

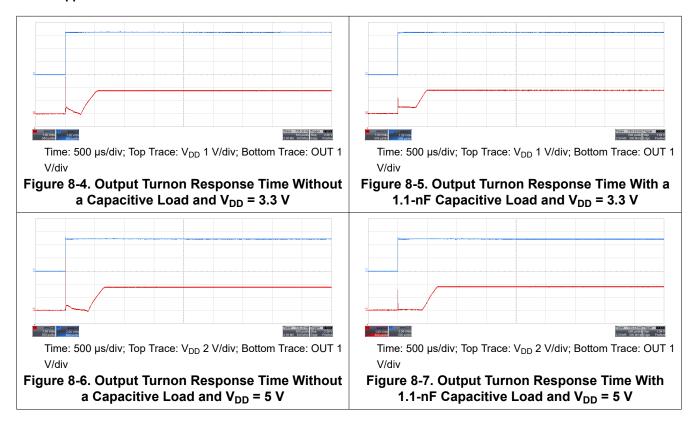
#### 8.2.2.1 Design Requirements

Because the power consumption of the LMT86 is less than 9  $\mu$ A, it can simply be powered directly from any logic gate output and therefore not require a specific shutdown pin. The device can even be powered directly from a microcontroller GPIO. In this way, it can easily be turned off for cases such as battery-powered systems where power savings are critical.

#### 8.2.2.2 Detailed Design Procedure

Simply connect the V<sub>DD</sub> pin of the LMT86 directly to the logic shutdown signal from a microcontroller.

#### 8.2.2.3 Application Curves



# 9 Power Supply Recommendations

The low supply current and supply range (2.2 V to 5.5 V) of the LMT86 allow the device to easily be powered from many sources. Power supply bypassing is optional and is mainly dependent on the noise on the power supply used. In noisy systems, it may be necessary to add bypass capacitors to lower the noise that is coupled to the output of the LMT86.

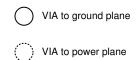


# 10 Layout

# 10.1 Layout Guidelines

The LMT86 The LMT86 is extremely simple to layout. If a power-supply bypass capacitor is used, it should be connected as shown in the *Layout Example*.

# 10.2 Layout Example



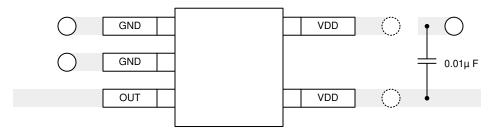


Figure 10-1. SC70 Package Recommended Layout

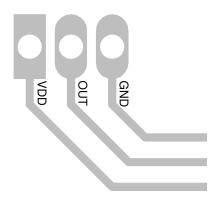


Figure 10-2. TO-92 LP Package Recommended Layout

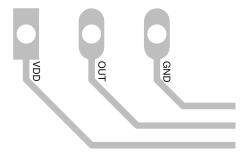


Figure 10-3. TO-92 LPM Package Recommended Layout

Submit Document Feedback

# 11 Device and Documentation Support

# 11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 11.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 11.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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## 11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# 11.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 12 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

# Changes from Revision E (October 2017) to Revision F (May 2024)

С	Changes from Revision D (June 2017) to Revision E (October 2017)	Page
•	Moved the automotive device to a standalone data sheet (SNIS201)	1
•	Changed TO-92 GND pin number from: 1 to: 3	<mark>3</mark>
•	Changed TO-92 V <sub>DD</sub> pin number from: 3 to: 1	3

C	hanges from Revision C (October 2015) to Revision D (June 2017)	Page
•	Updated data sheet text to the latest documentation and translations standards	1
	Added AEC-Q100 automotive qualification bullets to Features	
	Added Time Constant graph	
	Removed disk drivers, games, wireless transceivers, and cell phones from <i>Applications</i>	
	Added LPG (TO-92S) package	
	Added Figure 6-10 to Typical Characteristics	

Page



Changes from Revision B (May 2014) to Revision C (October 2015)	Page
Deleted all mentions of TO-126 package	1
Added TO-92 LPM pin configuration graphic	
	•
Changed KV to V	4
Changed Handling Ratings to ESD Ratings and moved Storage Temperature to Absolute Maximum able	
Changes from Revision A (June 2013) to Revision B (May 2014)	Page
Application and Implementation, Power Supply Recommendations, Layout, Device an	d Documentation
Added TO92 and TO126 package information	1
<ul> <li>Added TO92 and TO126 package information</li> <li>Changed from 450°C/W to 275 °C/W. New specification is derived using TI 's latest m</li> </ul>	
, ,	nethodology4
<ul> <li>Changed from 450°C/W to 275 °C/W. New specification is derived using TI 's latest m</li> </ul>	150°C5 s typically only 0.001

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
LMT86DCKR	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BSA
LMT86DCKR.A	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BSA
LMT86DCKR.B	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BSA
LMT86DCKT	Obsolete	Production	SC70 (DCK)   5	-	-	Call TI	Call TI	-50 to 150	BSA
LMT86LP	Active	Production	TO-92 (LP)   3	1800   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LP.A	Active	Production	TO-92 (LP)   3	1800   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LP.B	Active	Production	TO-92 (LP)   3	1800   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPG	Active	Production	TO-92 (LPG)   3	1000   BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPG.A	Active	Production	TO-92 (LPG)   3	1000   BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPG.B	Active	Production	TO-92 (LPG)   3	1000   BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPGM	Active	Production	TO-92 (LPG)   3	3000   AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPGM.A	Active	Production	TO-92 (LPG)   3	3000   AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPGM.B	Active	Production	TO-92 (LPG)   3	3000   AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPM	Active	Production	TO-92 (LP)   3	2000   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPM.A	Active	Production	TO-92 (LP)   3	2000   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86
LMT86LPM.B	Active	Production	TO-92 (LP)   3	2000   LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT86

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

# **PACKAGE OPTION ADDENDUM**

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(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF LMT86:

Automotive : LMT86-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

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# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width					
В0	Dimension designed to accommodate the component length					
K0	Dimension designed to accommodate the component thickness					
W Overall width of the carrier tape						
P1	Pitch between successive cavity centers					

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

	Device	Package Type	Package Drawing	l .	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ĺ	LMT86DCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3

**PACKAGE MATERIALS INFORMATION** 

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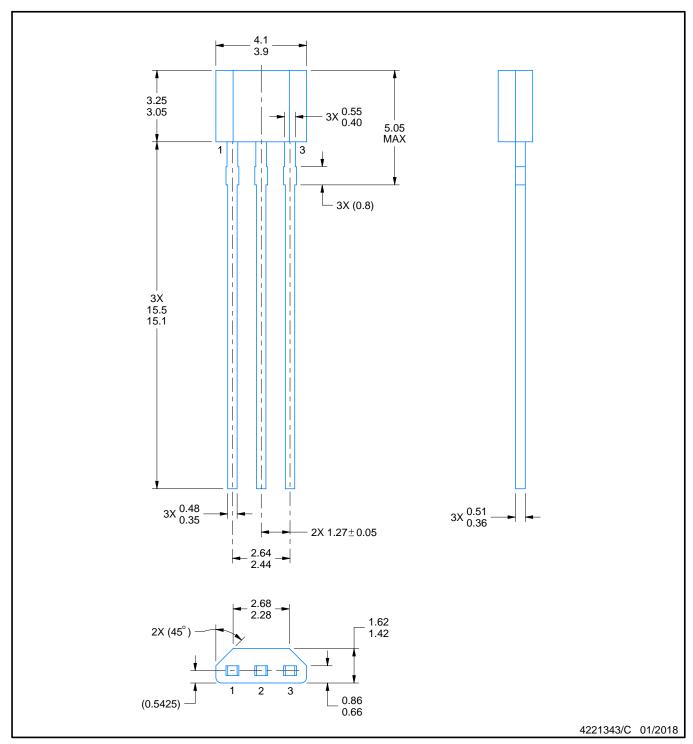


## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LMT86DCKR	SC70	DCK	5	3000	208.0	191.0	35.0	



TRANSISTOR OUTLINE



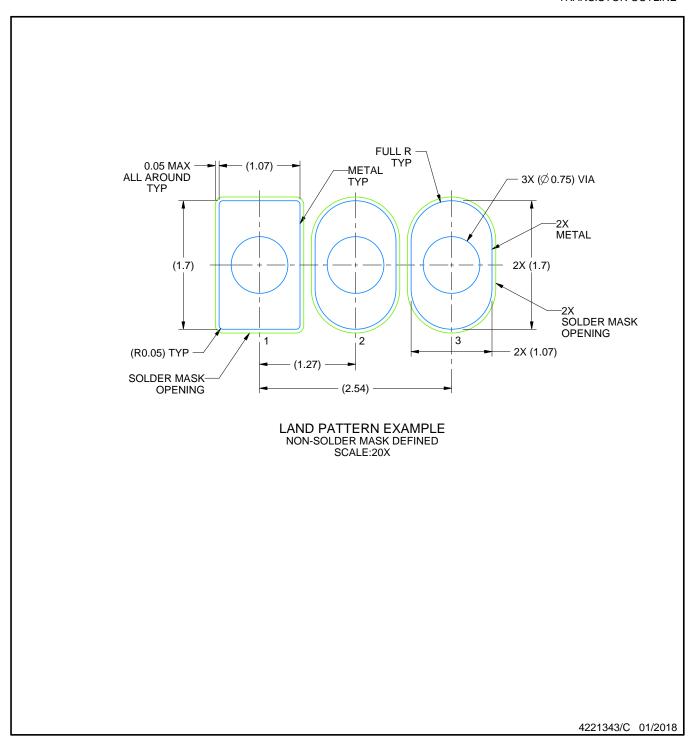
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



TRANSISTOR OUTLINE



TRANSISTOR OUTLINE





SMALL OUTLINE TRANSISTOR



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



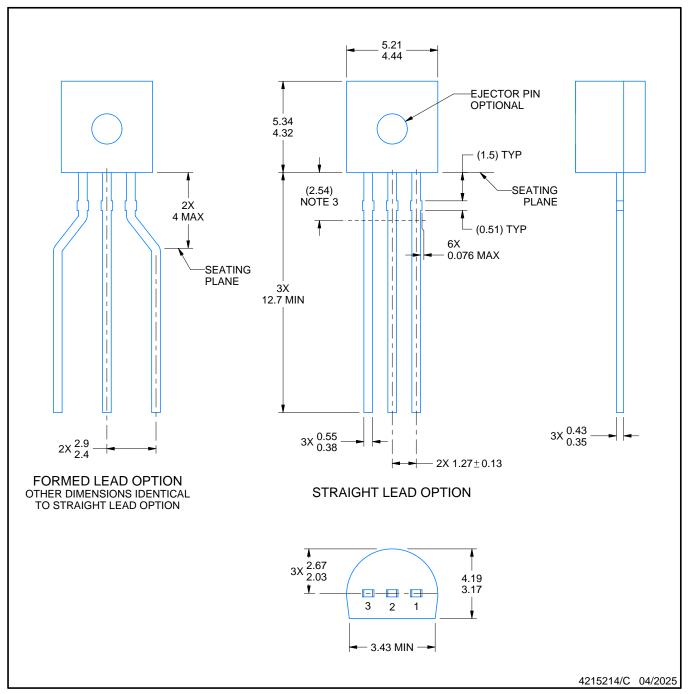
NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



TO-92 - 5.34 mm max height

TO-92



#### NOTES:

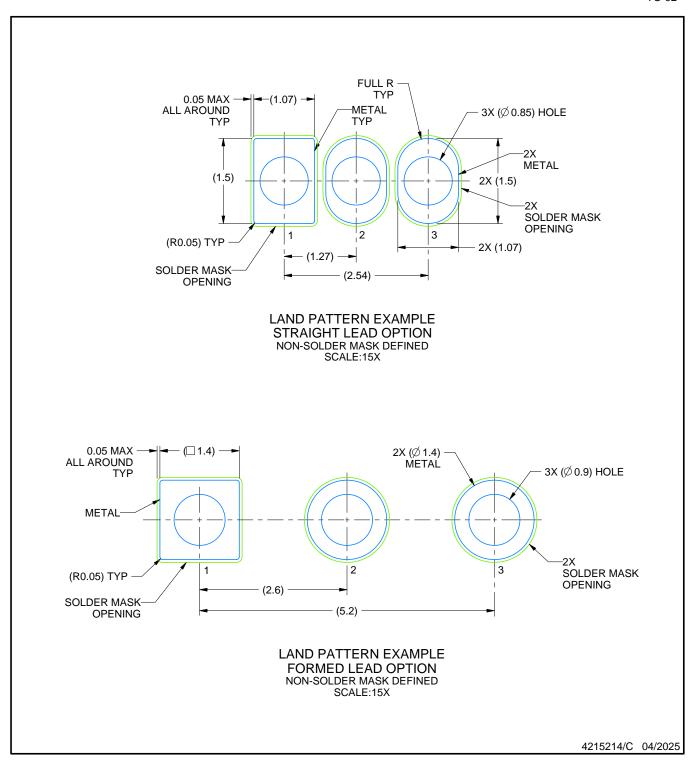
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. Lead dimensions are not controlled within this area. 4. Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

  - a. Straight lead option available in bulk pack only.
     b. Formed lead option available in tape and reel or ammo pack.
  - c. Specific products can be offered in limited combinations of shipping medium and lead options.
  - d. Consult product folder for more information on available options.

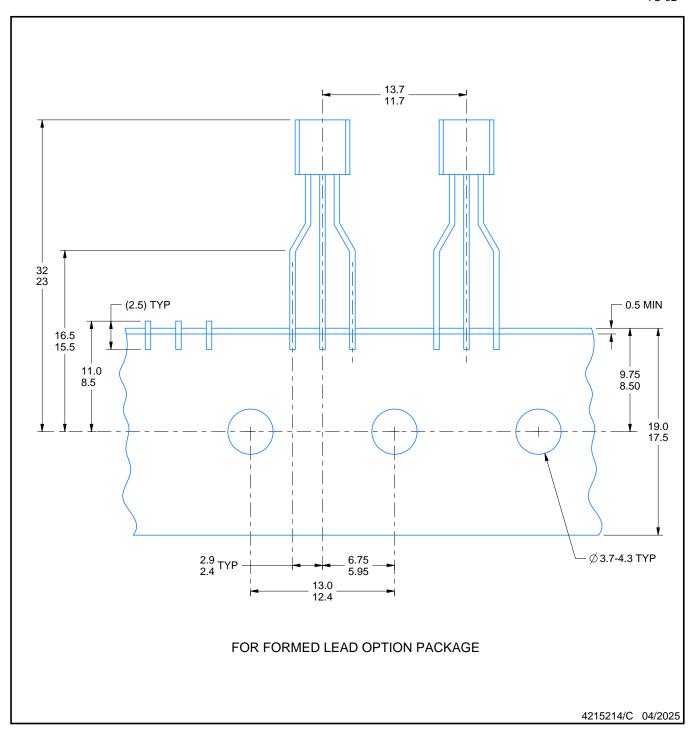


TO-92





TO-92





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